

**isc Silicon NPN Power Transistor**
**2SD1879**
**DESCRIPTION**

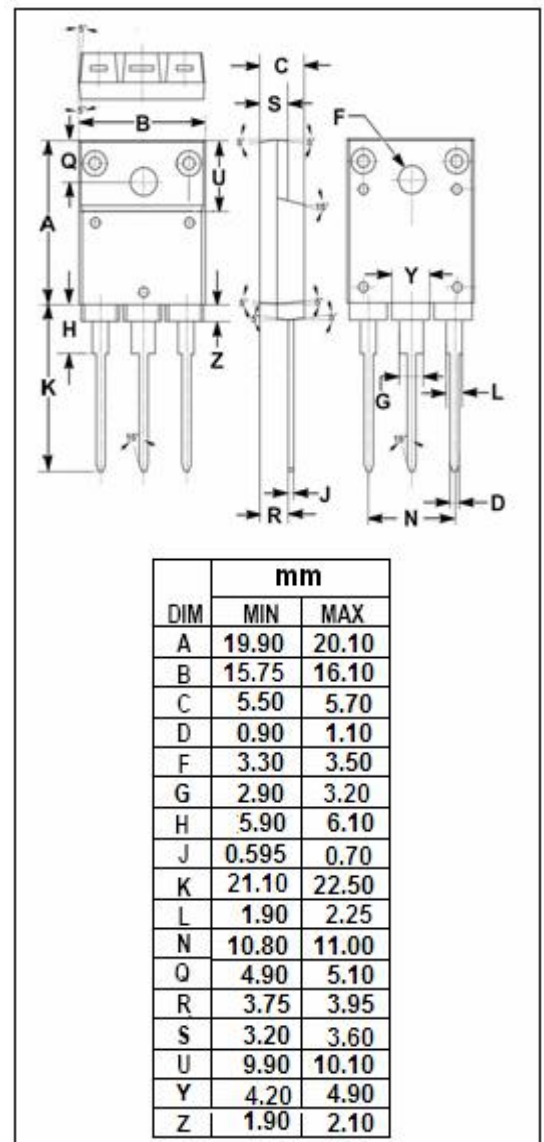
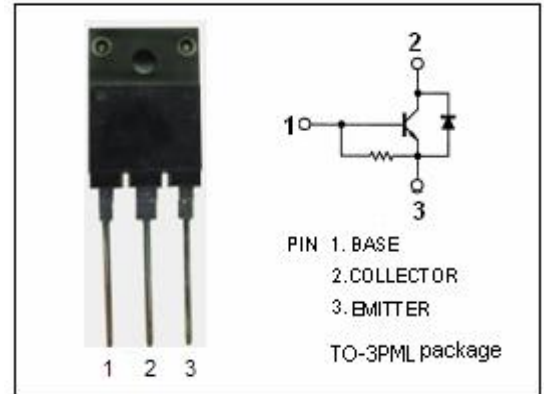
- High Breakdown Voltage-  
:  $V_{CBO} = 1300V$  (Min)
- High Switching Speed
- High Reliability
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Color TV horizontal deflection output
- Color display horizontal deflection output

**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	1300	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current- Continuous	6	A
$I_{CP}$	Collector Current-Pulse	20	A
$P_C$	Collector Power Dissipation @ $T_a = 25^\circ C$	3.0	W
	Collector Power Dissipation @ $T_c = 25^\circ C$	60	
$T_J$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ C$



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**ELECTRICAL CHARACTERISTICS**

 T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	800			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 800V ; I <sub>E</sub> = 0			10	μ A
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = 1300V ; R <sub>BE</sub> = 0			1.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V ; I <sub>C</sub> = 0	40		130	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V	8			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 5A ; V <sub>CE</sub> = 5V	5		10	
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 6A			2.0	V
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 4A , I <sub>B1</sub> = 0.8A ; I <sub>B2</sub> = -1.6A P <sub>W</sub> =20 μ s; Duty Cycle ≤ 1%			0.3	μ s

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